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Renesas Technology Corp. Customer Support Dept. April 1, 2003



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### **HSK122**

### Silicon Epitaxial Planar Diode for High Voltage Switching

## RENESAS

ADE-208-172D (Z)

Rev.4 Dec. 2000

#### Features

- High reverse voltage. ( $V_R = 400 \text{ V}$ )
- LLD package is suitable for high density surface mounting and high speed assembly.

#### **Ordering Information**

Type No.	Cathode band	Package Code
HSK122	Orange	LLD
Pin Arrangement	col	96-
	Cathode band	
	Cathode band	1. Cathode 2. Anode

#### **HSK122**

#### **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Value	Unit
Peak reverse voltage	V <sub>BM</sub>	410	V
Reverse voltage	V <sub>R</sub>	400	V
Peak forward current	I <sub>FM</sub>	625	mA
Non-Repetitive peak forward surge current	I <sub>FSM</sub> * <sup>1</sup>	1	А
Average forward current	I <sub>o</sub>	150	mA
Junction temperature	Tj	175	°C
Storage temperature	Tstg	–65 to + <mark>17</mark> 5	°C

Note: Within 1s forward surge current.

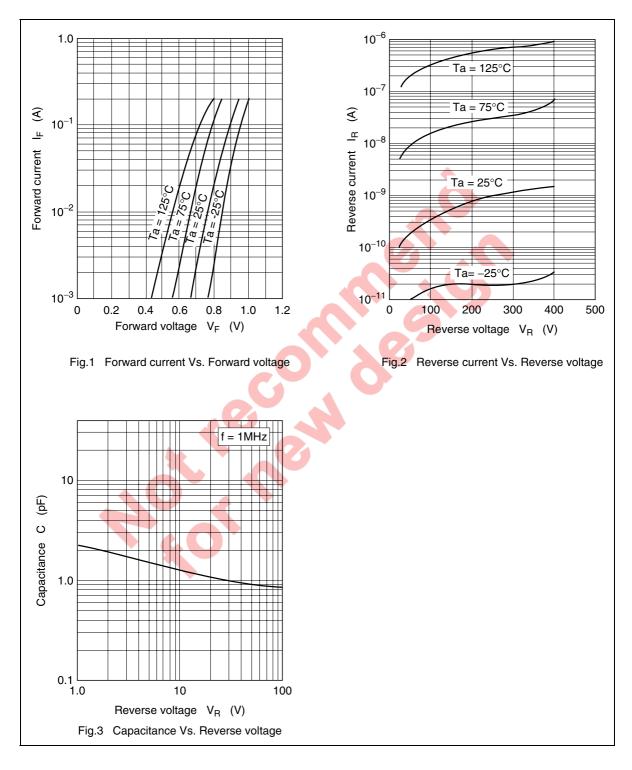
5-1-1

#### **Electrical Characteristics**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Min	Тур	Max	Unit	Test Condition
Forward voltage	V <sub>F</sub>	_	6	1.2	V	I <sub>F</sub> = 100 mA
Reverse current	I <sub>R</sub>	-		1.0	μΑ	V <sub>R</sub> = 400 V
Capacitance	С		-	10	pF	$V_{_{R}} = 0 V, f = 1 MHz$
Reverse recovery time	t <sub>rr</sub>	5	-	10	μs	$I_{_{\rm F}}$ = 30 mA, $V_{_{\rm R}}$ = 10 V, $R_{_{\rm L}}$ = 2 k $\Omega$

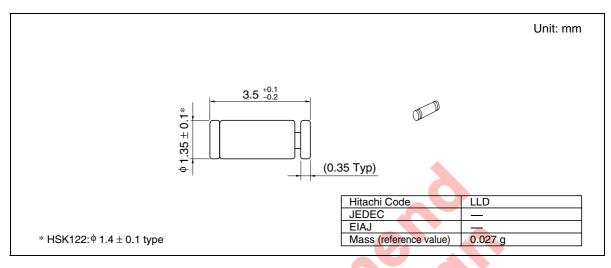
#### **Main Characteristic**





#### **HSK122**

#### **Package Dimensions**





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